

#### **TS393**

#### **Dual Voltage Comparator**

SOP-8





- 2. Input A (-)
- 3. Input A (+)
- 4. Gnd
- 5. Input B (+)
- 6. Input B (-)
- 7. Output B
- 8. Vcc

# Supply Voltage Range -18 V to 18V Dual Channel Comparator

#### **General Description**

The TS393 is dual independent precision voltage comparators capable of single-supply or split-supply operation. The specifications as low as 2.0 mV make this device an excellent ground level with single-supply operation. Input offset-voltage selection for many applications in consumer automotive, and It is designed to permit a common mode range-to- industrial electronics.

The TS393 is offered in 8 pin SOP-8 and DIP-8 package.

#### **Features**

- Output voltage compatible with DTL, ECL, TTL, MOS and CMOS Logic Levels
- ♦ Low input bias current -25nA
- ♦ Low input offset current -5.0nA
- ♦ Input common mode range to ground level
- Differential Input voltage range equal to power supply voltage
- Very low current drain independent of supply voltage - 0.4mA
- ♦ Wide single-supply range 2.0Vdc to 36Vdc
- ♦ Split-supply range ±1.0Vdc to ±18Vdc

# Block Diagram In A(-) 2 In A(-) 3

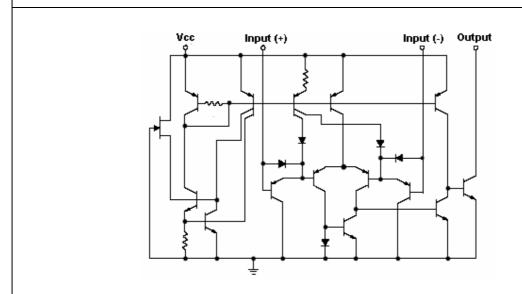


Pin 4 = Gnd Pin 8 = Vcc

#### **Ordering Information**

Part No.	Operating Temp.	Package
TS393CD	0 ~ +70 °C	DIP-8
TS393CS		SOP-8

#### Schematic (each comparator)





Absolute Maximum Rating			
Supply Voltage	Vcc	+36 or ±18	Vdc
Differential Input Voltage	V <sub>IDR</sub>	36	Vdc
Input Common Mode Voltage Range	V <sub>ICR</sub>	-0.3 to 36	Vdc
Input Current (note 2)	lin	50	mA
Output Short Circuit to Ground	Isc	Continuous	
Output Sink Current (note 1)	Isink	20	mA
Power Dissipation @ Ta=25 °C		570	mW
Derate above 25 °C	1/Rθja	5.7	mW/°C
Operating Junction Temperature Range	T <sub>J</sub>	0 ~ +125	°C
Storage Temperature Range	T <sub>STG</sub>	-65 ~ +150	°C
Lead Temperature 1.6mm(1/16") from case for 10Sec.	T <sub>LEAD</sub>	260	°C

### **Electrical Characteristics**

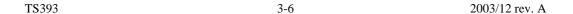
(V<sub>CC</sub> = 5V, T<sub>LOW</sub> ≤ Ta ≤T<sub>HIGH</sub>; unless otherwise specified.)

Characteristics	Symbol	Test condition	Min	Тур	Max	Unit
Input Offset Voltage (note 3)	Vio	Ta =25 °C		±1.0	±5.0	mV
		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>			9.0	
Input Offset Current	lio	Ta =25 °C		±5.0	±50	nA
		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>			±150	
Input Offset Current (note 4)	I <sub>IB</sub>	Ta =25 °C		25	250	nA
		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>			400	
Input Common Mode	V <sub>ICR</sub>	Ta =25 °C	0		V <sub>CC</sub> -1.5	Volts
Voltage Range (note 5)		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>	0		V <sub>CC</sub> -2.0	
Voltage Gain	A <sub>VOL</sub>	R <sub>L</sub> ≥15K, Vcc = 15Vdc.	50	200		V/mV
		Ta =25 °C				
Large Signal Response		Vin = TTL Logic Swing.		300		nS
Time		Vref = 1.4Vdc, VRL = 5Vdc.				
		RL 5.1KΩ, Ta =25 °C				
Response Time (note 6)	t <sub>TLH</sub>	VRL = 5Vdc, RK = $5.1$ K $\Omega$		1.3		uS
		Ta =25 °C				
Input Differential Voltage	$V_{ID}$	All Vin ≥ Gnd or V-Supply			$V_{CC}$	V
(note 7)		(if used)				
Output Sink Current	I <sub>SINK</sub>	Vin-≥1Vdc, Vin+=0Vdc,	60	16		mA
		V <sub>O-</sub> ≤1 Vdc, Ta =25 °C				
Output Saturation Voltage	V <sub>OL</sub>	Vin- ≥1Vdc, Vin+=0,				mV
		I <sub>SINK</sub> ≤4mA, Ta =25 °C		150	400	
		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>			700	
Output Leakage Current	I <sub>OL</sub>	Vin-=0V, Vin+≥1Vdc, P=5Vdc.				nA
		Ta =25 °C		0.1		
		Vin-=0V, Vin+≥1V, V <sub>O</sub> =30Vdc				
		T <sub>LOW</sub> ≤ Ta ≤T <sub>HIGH</sub>			1000	
Supply Current	Icc	R <sub>L</sub> = ∞, Ta =25 °C		0.4	1.0	mA
		$R_L = \infty$ , $V_{CC} = 30 \text{ V}$			2.5	



#### **Electrical Characteristics (Continues)**

- Note 1. The max. Output current may be as high as 20mA, independent of the magnitude of  $V_{CC}$ , output short circuits to  $V_{CC}$  can cause excessive heating and eventual destruction.
- Note 2. This magnitude of input current will only occur if the input leads are driven more negative than ground or the negative supply voltage. This is due to the input PNP collector base junction becoming forward biased acting as an input clamp diode. There is also a lateral PNP parasitic transistor action on the IC chip. This phenomena can cause the output voltage of the comparators to go to the  $V_{CC}$  voltage level (or ground if overdrive is large) during the time the input is driven negative. This will not destroy the device and normal output states will recover when the inputs become -0.3V of ground or negative supply.
- Note 3. At output switch point,  $V_0$ =1.4Vdc,  $R_S$ =0 $\Omega$  with  $V_{CC}$  from 5Vdc to 30Vdc, and over the full input common-mode
- Note 4. Due to the PNP transistor inputs, bias current will flow out of the inputs, this current is essentially constant independent of the output state, therefore, no loading changes will exist on the input lines.
- Note 5. Input common mode of either input should not be permitted to go more than 0.3V negative of ground or minus supply. The upper limit of common mode range is  $V_{CC}$  1.5V but either or both inputs can betaken to as high as 30volts without damage.
- Note 6. Response time is specified with a 100mV step and 5.0mV of overdrive. With larger magnitudes of overdrive faster response times are obtainable.
- Note 7. The comparator will inhibit proper output state if one of the inputs is become greater than  $V_{CC}$ , the other input must remain within the common mode range. The low input state must not be less than -0.3volts of ground of minus supply.





#### **Applications Information**

This dual comparator feature high gain, wide bandwidth characteristics. This gives the device oscillation tendencies if the outputs are capacitive coupled to the inputs via stray capacitance. This oscillation manifests itself during output transitions ( $V_{OL}$  to  $V_{OH}$ ). To alleviate this situation input resistors<10K $\Omega$  should be used. The addition of positive feedback (<10 mV) is also recommended.

It is good design practice to ground all unused pins. Differential input voltages may be larger than supply voltage without damaging the comparator's inputs. Voltages more negative than -0.3V should not be used.

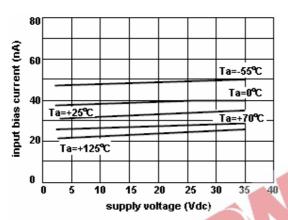


Figure 1. input bias current vs power supply voltage

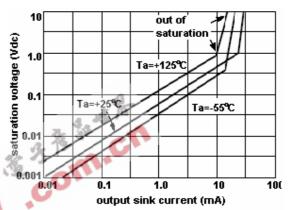


Figure 2. output saturation voltage vs output sink current

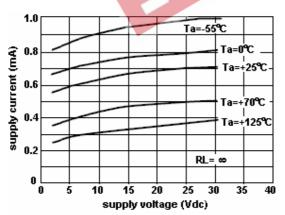
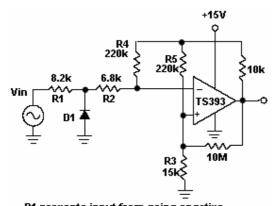


Figure 3. power supply current vs power supply voltage

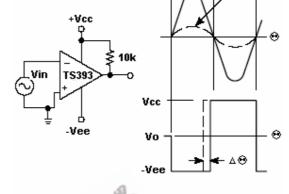


#### **Electrical Characteristics Curve**



D1 prevents input from going engative by more than 0.6V, R1 + R2 = R3 R3 <= R5 / 10 for small error in zero crosing

Figure 4. zero crossing detector (single supply)



Vin

Vin(min)

Vin(min)=0.4V peak for 1% phase distortion (△ 🏵)

Figure 5. zero crossing detector (split supply)

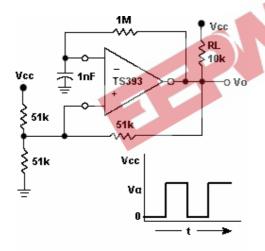


Figure 6. free-running square-wave oscillator

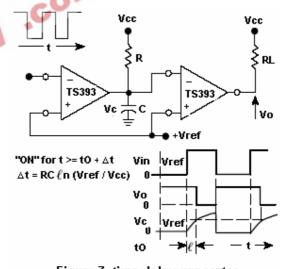
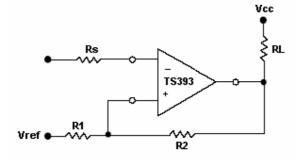


Figure 7. time delay generator



Rs = R1 | | R2  
Vth1 = Vref + 
$$\frac{(Vcc - Vref) * R1}{R1 + R2 + RL}$$

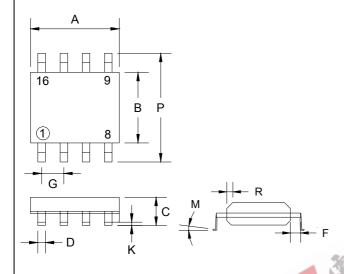
Vth2 = Vref -  $\frac{(Vref - Vo low) * R1}{R1 + R2}$ 

Figure 8. comparator with hysteresis

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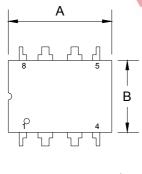


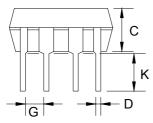
## **SOP-8 Mechanical Drawing**

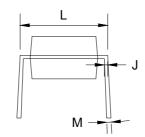


SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27 (typ)		0.05 (typ)		
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

# **DIP-8** Mechanical Drawing







SOP-8 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	9.07	9.32	0.357	0.367	
В	6.22	6.48	0.245	0.255	
С	3.18	4.45	0.125	0.135	
D	0.35	0.55	0.019	0.020	
G	2.54 (typ)		0.10 (typ)		
J	0.29	0.31	0.011	0.012	
K	3.25	3.35	0.128	0.132	
L	7.75	8.00	0.305	0.315	
М	-	10°	-	10°	